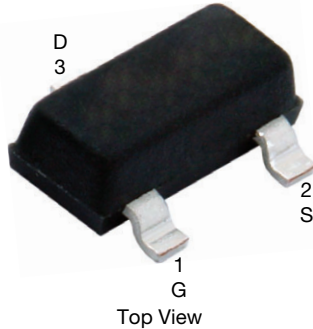


Automotive P-Channel 12 V (D-S) 175 °C MOSFET

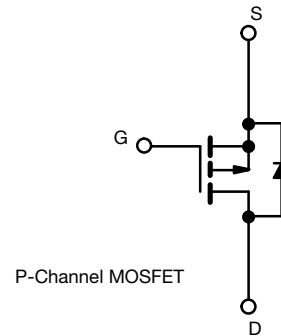
SOT-23 (TO-236)

Marking Code: 8D

PRODUCT SUMMARY	
V_{DS} (V)	-12
$R_{DS(on)}$ (Ω) at $V_{GS} = -4.5$ V	0.050
$R_{DS(on)}$ (Ω) at $V_{GS} = -2.5$ V	0.068
$R_{DS(on)}$ (Ω) at $V_{GS} = -1.8$ V	0.100
I_D (A)	-5
Configuration	Single

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified ^c
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

 AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE


P-Channel MOSFET

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2315ES (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	-12	V
Gate-source voltage		V_{GS}	± 8	
Continuous drain current	$T_C = 25$ °C	I_D	-5	A
	$T_C = 125$ °C		-3	
Continuous source current (diode conduction)		I_S	-2.5	
Pulsed drain current ^a		I_{DM}	-20	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	-11	
Single pulse avalanche energy		E_{AS}	6	mJ
Maximum power dissipation ^a	$T_C = 25$ °C	P_D	2	W
	$T_C = 125$ °C		0.67	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^b	R_{thJA}	175	°C/W
Junction-to-foot (drain)		R_{thJF}	75	

Notes

- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR4 material)
- Parametric verification ongoing.



SPECIFICATIONS ($T_C = 25\text{ }^\circ\text{C}$, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$		-12	-	-	V
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$		-0.45	-	-1	
Gate-source leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 8\text{ V}$		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = -12\text{ V}$	-	-	-1	μA
		$V_{GS} = 0\text{ V}$	$V_{DS} = -12\text{ V}, T_J = 125\text{ }^\circ\text{C}$	-	-	-50	
		$V_{GS} = 0\text{ V}$	$V_{DS} = -12\text{ V}, T_J = 175\text{ }^\circ\text{C}$	-	-	-150	
On-state drain current ^a	$I_{D(on)}$	$V_{GS} = -4.5\text{ V}$	$V_{DS} \leq -5\text{ V}$	-10	-	-	A
Drain-source on-state resistance ^a	$R_{DS(on)}$	$V_{GS} = -4.5\text{ V}$	$I_D = -3.5\text{ A}$	-	0.042	0.050	Ω
		$V_{GS} = -4.5\text{ V}$	$I_D = -3.5\text{ A}, T_J = 125\text{ }^\circ\text{C}$	-	-	0.066	
		$V_{GS} = -4.5\text{ V}$	$I_D = -3.5\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	-	0.075	
		$V_{GS} = -2.5\text{ V}$	$I_D = -3\text{ A}$	-	0.059	0.068	
		$V_{GS} = -1.8\text{ V}$	$I_D = -2\text{ A}$	-	0.084	0.100	
Forward transconductance ^b	g_{fs}	$V_{DS} = -5\text{ V}, I_D = -1.6\text{ A}$		-	7	-	S
Dynamic ^b							
Input capacitance	C_{iss}	$V_{GS} = 0\text{ V}$	$V_{DS} = -6\text{ V}, f = 1\text{ MHz}$	-	695	870	μF
Output capacitance	C_{oss}			-	265	335	
Reverse transfer capacitance	C_{rss}			-	190	240	
Total gate charge ^c	Q_g	$V_{GS} = -4.5\text{ V}$	$V_{DS} = -6\text{ V}, I_D = -3.85\text{ A}$	-	9	13	nC
Gate-source charge ^c	Q_{gs}			-	1	-	
Gate-drain charge ^c	Q_{gd}			-	2.4	-	
Gate resistance	R_g	$f = 1\text{ MHz}$		2.4	4.9	12.3	Ω
Turn-on delay time ^c	$t_{d(on)}$	$V_{DD} = -6\text{ V}, R_L = 1.6\text{ }\Omega$ $I_D \cong -3.85\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 1\text{ }\Omega$		-	17	26	ns
Rise time ^c	t_r			-	19	29	
Turn-off delay time ^c	$t_{d(off)}$			-	28	42	
Fall time ^c	t_f			-	13	20	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed current ^a	I_{SM}			-	-	-20	A
Forward voltage	V_{SD}	$I_F = -2\text{ A}, V_{GS} = 0\text{ V}$		-	-0.8	-1.2	V

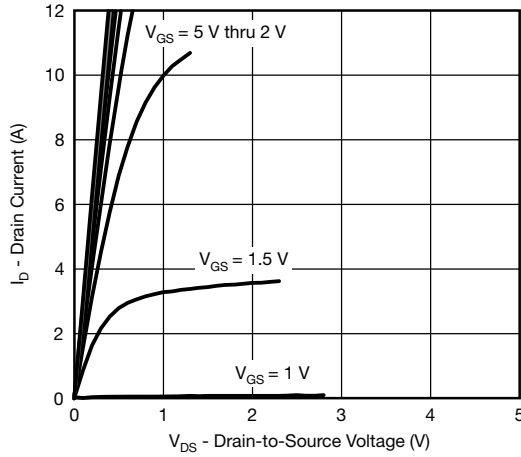
Notes

- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
- Guaranteed by design, not subject to production testing
- Independent of operating temperature

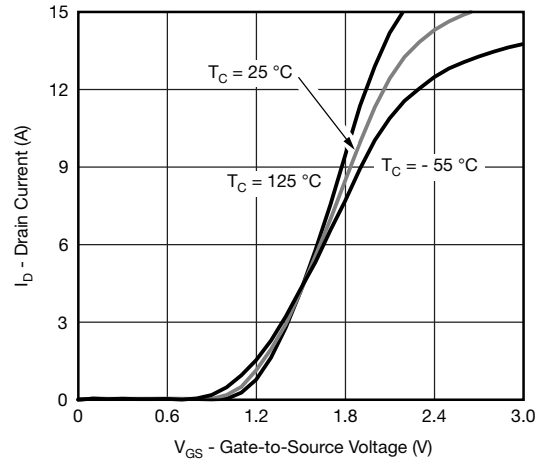
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



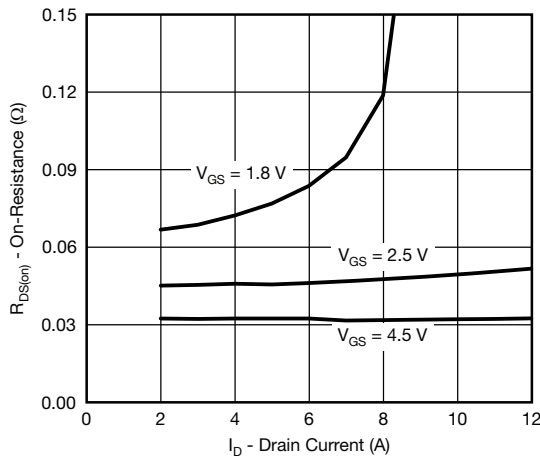
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



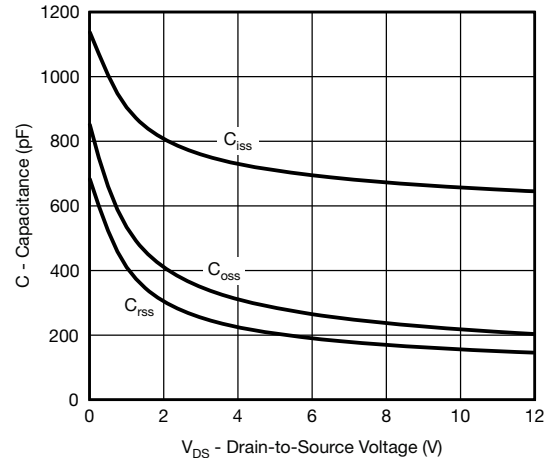
Output Characteristics



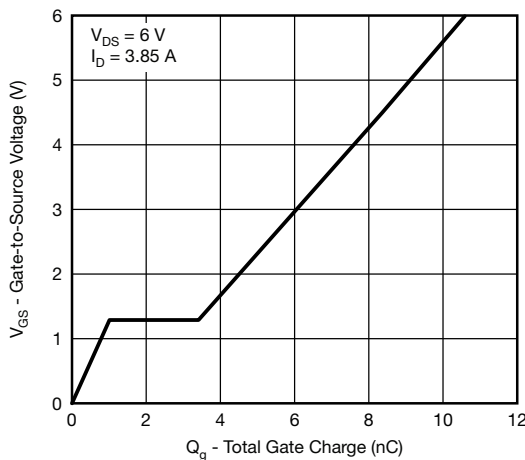
Transfer Characteristics



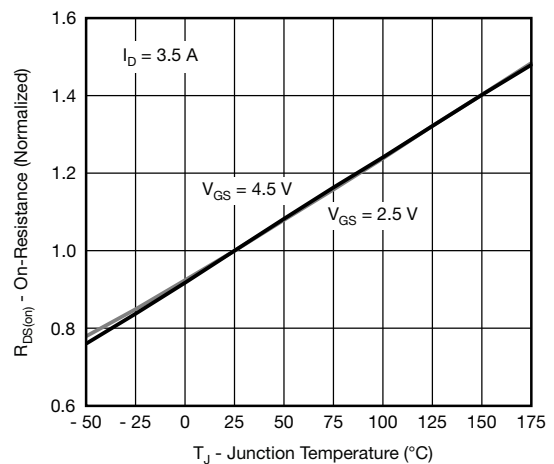
On-Resistance vs. Drain Current



Capacitance



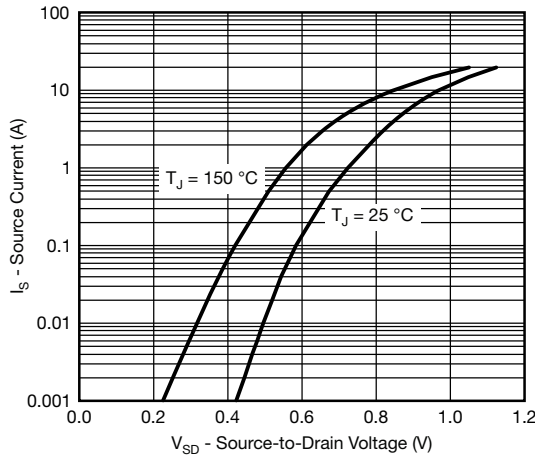
Gate Charge



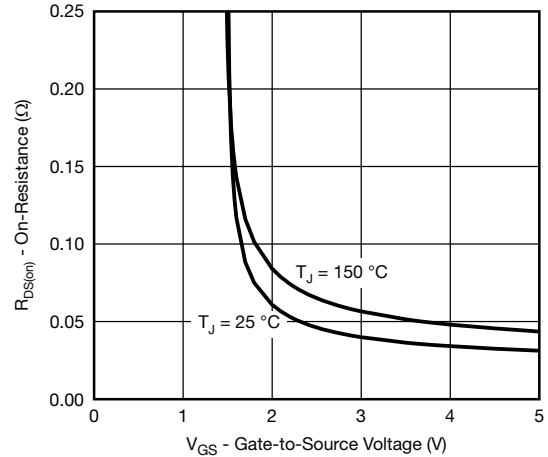
On-Resistance vs. Junction Temperature



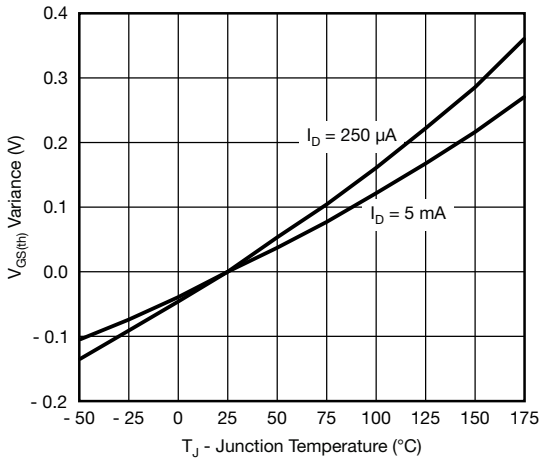
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



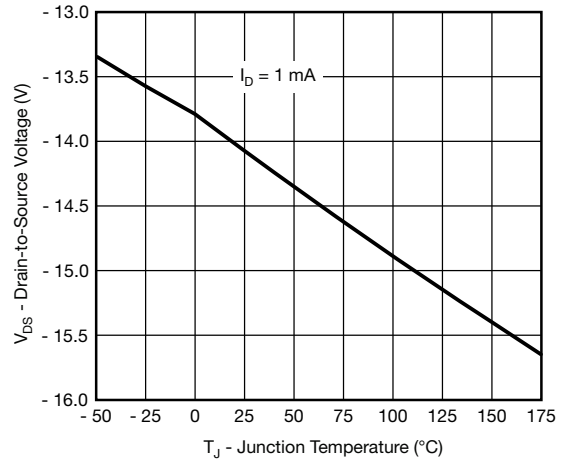
Source-Drain Diode Forward Voltage



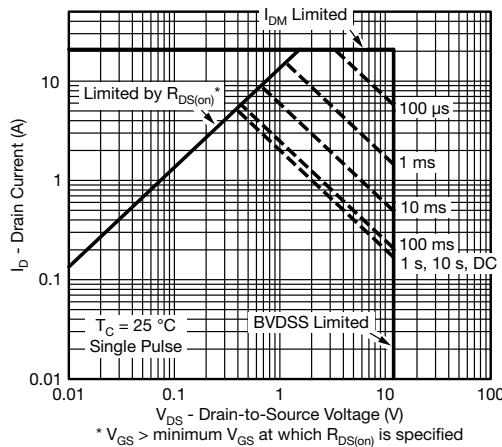
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



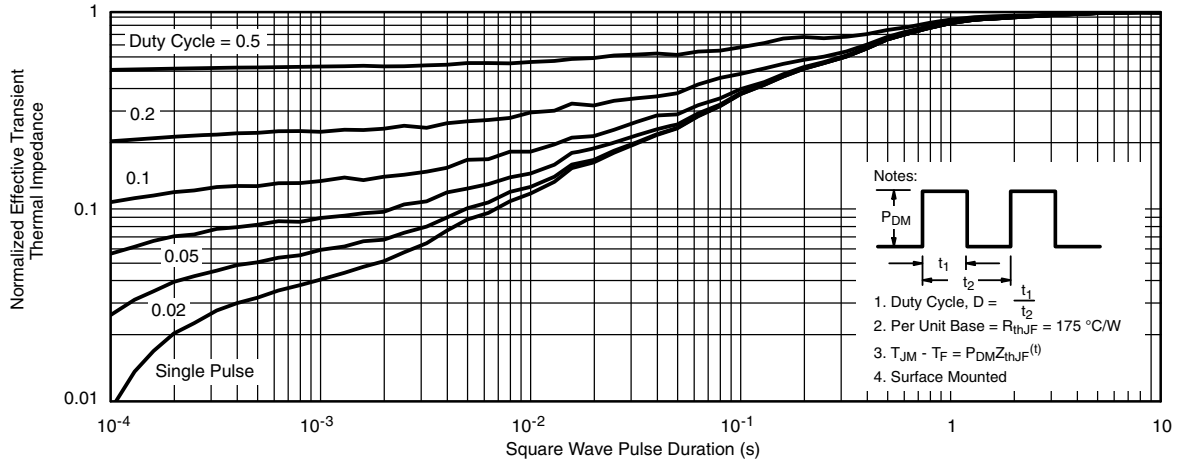
Drain Source Breakdown vs. Junction Temperature



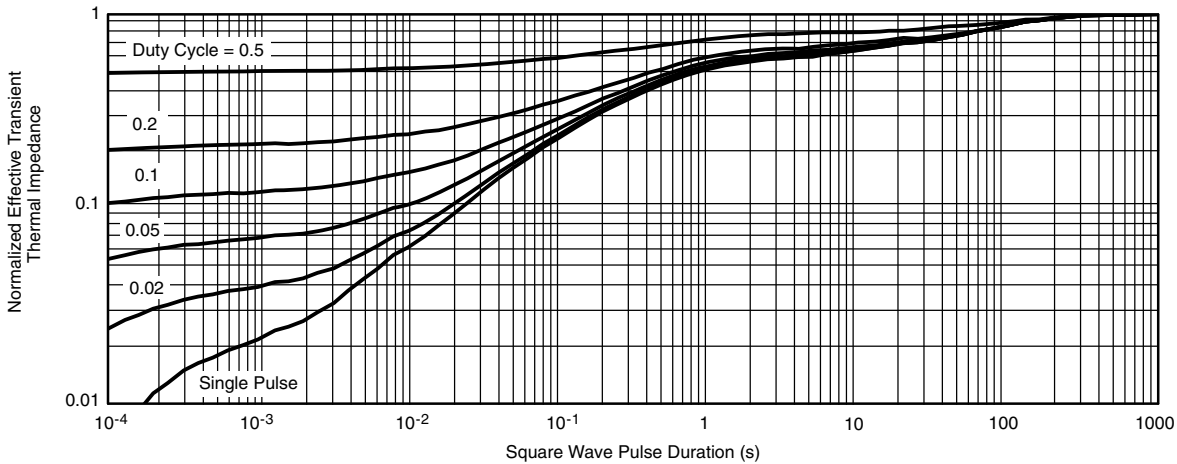
Safe Operating Area



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot



Normalized Thermal Transient Impedance, Junction-to-Ambient

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^\circ\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Foot ($25\text{ }^\circ\text{C}$)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A ₁	0.01	0.10	0.0004	0.004
A ₂	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E ₁	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e ₁	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L ₁	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°

ECN: S-03946-Rev. K, 09-Jul-01
 DWG: 5479

RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads
Dimensions in Inches/(mm)

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